MLX92221-AAA

2-Wire Hall Effect Latch



Features and Benefits

- Wide operating voltage range: from 2.7V to 24V
- Integrated self-diagnostics
- Chopper-stabilized amplifier stage
- Programmable Built-in negative temperature coefficient
- Reverse Supply Voltage Protection
- Under-Voltage Lockout Protection
- Thermal Protection
- High ESD rating / Excellent EMC performance

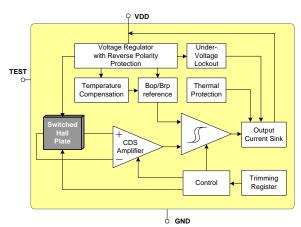
Applications

- Automotive, Consumer and Industrial
- Wiper motor
- Window lifter
- Seatbelt buckle
- Seat positioning
- Sunroof/Tailgate opener
- Electrical power steering

Ordering information

Part No.	Temperature Code	Package Code	Comment
MLX92221LUA-AAA-xxx-BU	L (-40°C to 150°C)	UA (TO92-3L)	BU (Bulk)
MLX92221LSE-AAA-xxx-RE	L (-40°C to 150°C)	SE (TSOT-23)	RE (Reel)

1. Functional Diagram



2. General Description

The Melexis MLX92221 is a new generation of Hall-effect switches designed in mixed signal submicron CMOS technology.

The device integrates a voltage regulator, Hall sensor with advanced offset cancellation system and a current sink-configured output driver, all in a single package.

Based on a brand-new platform, the magnetic core is using an improved offset cancellation system allowing faster and more accurate processing while being temperature insensitive and stress independent. In addition, a temperature coefficient is implemented to compensate the natural behaviour of certain types of magnets becoming weaker with rise in temperature. The included voltage regulator operates from 2.7 to 24V, hence covering a wide range of applications. With the builtin reverse voltage protection, a serial resistor or diode on the supply line is not required so that even remote sensors can be specified for low voltage operation down to 2.7V while being reverse voltage tolerant.

In an event of a drop below the minimum supply voltage during operation, the under-voltage lock-out protection will automatically freeze the device, preventing the electrical perturbation to affect the magnetic measurement circuitry. The output current state is therefore only updated based on a proper and accurate magnetic measurement result.

The two-wire interface not only saves one wire, but also allows implementation of diagnostic functions as reverse polarity connection and malfunction detection. The on-chip thermal protection also switches off the output if the junction temperature increases above an abnormally high threshold. It will automatically recover once the temperature decreases below a safe value.

With latching magnetic characteristics, the supply current state is turned high by a sufficiently strong South Pole facing the package branded side. Toggling the state of the supply current from high to low is possible by applying low or no magnetic field.

The MLX92221 is delivered in a Green and RoHS compliant Plastic Single-in-Line (TO-92 flat) for through-hole mount or PCB-less design or in 3-pin Thin Small Outline Transistor (TSOT) for surface mount process



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11.2. TO92-3L (UA Package)	
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2-Wire Hall Effect Latch



3. Absolute Maximum Ratings

Parameter	Symbol	Value	Units
Supply Voltage ^(1, 2)	V_{DD}	+27	V
Supply Current ^(1, 2, 3)	I _{DD}	+20	mA
Supply Current ^(1, 3, 4)	I _{DD}	+50	mA
Reverse Supply Voltage (1, 2)	V _{DDREV}	-24	V
Reverse Supply Current (1, 2, 5)	IDDREV	-20	mA
Reverse Supply Current (1, 4, 5)	IDDREV	-50	mA
Maximum Junction Temperature (6)	TJ	+165	°C
Operating Temperature Range	T _A	-40 to 150	°C
Storage Temperature Range	Ts	-55 +165	°C
ESD Sensitivity – HBM ⁽⁷⁾	-	3000	V
ESD Sensitivity – MM ⁽⁸⁾	-	400	V
ESD Sensitivity – CDM ⁽⁹⁾	-	1000	V
Magnetic Flux Density	В	Unlimited	mT

Exceeding the absolute maximum ratings may cause permanent damage. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

¹ The maximum junction temperature should not be exceeded

- ² For maximum 1 hour
- ³ Including current through protection device
- ⁴ For maximum 1 second
- ⁵ Through protection device
- ⁶ For 1000 hours
- ⁷ Human Model according AEC-Q100-002 standard
- ⁸ Machine Model according AEC-Q100-003 standard
- ⁹ Charged Device Model according AEC-Q100-011 standard

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4. General Electrical Specifications

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DC Operating Parameters $V_{DD} = 2.7$ to 24V, $T_J = -40^{\circ}$ C to 165°C	(amess other wise specifica)

Parameter	Symbol	Test Conditions	Min	Typ ⁽¹⁾	Max	Units
Supply Voltage	V _{DD}	Operating	2.7	-	24	V
Reverse Supply Current	IDDREV	V _{DD} = -16V			1	mA
OFF Supply Current	IOFFLOW	V _{DD} = 3.5 to 24V	2	3.3	5	mA
OFF Supply Current	IOFFHigh	V _{DD} = 3.5 to 24V	5	6	6.9	mA
ON Supply Current	Ion	V _{DD} = 3.5 to 24V	12	14.5	17	mA
Safe Mode Supply Current	ITP	Thermal Protection activated	-	-	0.8	mA
Supply Current Rise/Fall Time (2)	trise/fall	V_{DD} = 12V, CLOAD = 50pF to GND	0.1	0.3	1	μs
Power-On Time (3,4,5)	ton	$V_{DD} = 5V$, $dV_{DD}/dt > 2V/us$	-	40	70	μs
Chopping Frequency	f _{CHOP}		260	340	-	kHz
Delay time ^(2,6)	to	Average value for 1000 successive switching events @10kHz, Square wave with B ≥ 3*B _{OPMAX} , tRISE = tFALL ≤20us	-	7.5	-	μs
Output Jitter (p-p) ^(2,7)	tjitter	Square wave with B ≥ 3*B _{OPMAX} over 1000 successive switching events @1kHz	-	±3.3	-	μs
Maximum Switching Frequency (2,8)	f _{sw}	$B \ge 3^*B_{OPMAX}$ and square wave magnetic field	30	50	-	kHz
Under-voltage Lockout Threshold	V _{UVL}		-	2	2.7	V
Under-voltage Lockout Reaction time ⁽²⁾	tuvl		-	1	-	μs
Thermal Protection Threshold	Tprot	Junction temperature	-	190 ⁽⁹⁾	-	°C
Thermal Protection Release	TREL	Junction temperature	-	180 ⁽⁹⁾	-	°C
Safe Mode Supply Current	I _{TP}	Thermal Protection activated	-	-	0.8	mA
UA Package Thermal Resistance	Rтн	Single layer (1S) Jedec board, zero LFPM		200		°C/W
TSOT Package Thermal Resistance	Rтн	Single layer (1S) Jedec board, zero LFPM		300		°C/W

¹ Typical values are defined at $T_A = +25^{\circ}C$ and $V_{DD} = 12V$

³ The Power-On Time represents the time from reaching $V_{DD} = V_{POR}$ to the first refresh of the supply current state.

⁹ *T*_{PROT} and *T*_{REL} are the corresponding junction temperature values.

² Guaranteed by design and verified by characterization, not production tested

⁴ Power-On Slew Rate is not critical for the proper device start-up.

⁵ B>B_{OPmax} + 1 mT for direct output sensors, or B<B_{RPmin} - 1 mT.

⁶ Delay Time is the time from magnetic threshold reached to the start of the supply current switching.

⁷ Output jitter is the unpredictable deviation of the Delay time

⁸ Maximum switching frequency corresponds to the maximum frequency of the applied magnetic field which is detected without loss of pulses



5. Specifications

5.1. MLX92221LSE-AAA-001

DC Operating Parameters V_{DD} = 3.5V to 24V, T_J = -40°C to 165°C

Test Condition	Operating Point B _{OP} (mT)				Release Poir B _{RP} (mT)	nt	TC (ppm/°C)	I _{ОFF} (mA)	Active Pole
	Min	Тур(1)	Max	Min	Typ ⁽¹⁾	Max	Typ ⁽¹⁾	Typ ⁽¹⁾	
T _J = -40°C	7.4	11.8	16.3	-7.4	-11.8	-16.3			
T _J = 25°C	7.4	11.8	16.3	-7.4	-11.8	-16.3	0 ⁽²⁾	0 ⁽²⁾ 6	South pole
T _J = 150°C	7.4	11.8	16.3	-7.4	-11.8	-16.3			

5.2. MLX92221LSE-AAA-002

DC Operating Parameters V_{DD} = 3.5V to 24V, T_J = -40°C to 165°C

Test Condition	Operating Point B _{OP} (mT)				Release Poiı B _{RP} (mT)	nt	TC (ppm/°C)	I _{OFF} (mA)	Active Pole
	Min	Typ ⁽¹⁾	Max	Min	Typ ⁽¹⁾	Max	Тур ⁽¹⁾	Typ ⁽¹⁾	
T _J = -40°C	4.1	6.8	9.6	-9.6	-6.8	-4.1			
T」 = 25°C	4.1	6	7.9	-7.9	- 6	-4.1	-2000 ⁽²⁾	6	South pole
T」 = 150°C	1.8	4.5	7.1	-7.1	-4.5	-1.8			

5.3. MLX92221LSE-AAA-003

DC Operating Parameters V_{DD} = 3.5V to 24V, T_J = -40°C to 165°C

Test Condition	tion Operating Point Release Point B _{OP} (mT) B _{RP} (mT)				TC (ppm/ºC)	I _{OFF} (mA)	Active Pole		
	Min	Typ(1)	Max	Min	Typ(1)	Max	Typ ⁽¹⁾	Typ ⁽¹⁾	
T _J = -40°C	0.5	2	3.2	-3.2	-2	-0.5			
T」 = 25°C	0.8	1.8	2.8	-2.8	-1.8	-0.8	0 ⁽²⁾	6	South pole
T _J = 150°C	0.3	1.8	3.3	-3.3	-1.8	-0.3			

1 Typical values are defined at T_A =+25°C and V_{DD} =12V

2 Temperature coefficient is calculated using the following formula:

$$\frac{(B_{OPT2} - B_{RPT2}) - (B_{OPT1} - B_{RPT1})}{(B_{OP25^{\circ}C} - B_{RP25^{\circ}C}) \times (T_2 - T_1)} * 10^6, ppm/^{\circ} C; T_1 = 25^{\circ} C; T_2 = 150^{\circ} C$$

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5.4. MLX92221LUA-AAA-004

DC Operating Parameters V _D	_D = 3.5V to 24V, T _J = -40°C to 165°C

Test Condition	(Dperating Po B _{OP} (mT)	int		Release Poiı B _{RP} (mT)	nt	TC (ppm/°C)	I _{OFF} (mA)	Active Pole
	Min	Typ ⁽¹⁾	Max	Min	Typ ⁽¹⁾	Max	Тур ⁽¹⁾	Typ ⁽¹⁾	
T」 = -40°C	4.1	6.8	9.6	-9.6	-6.8	-4.1			South pole
T」 = 25°C	4.1	6	7.9	-7.9	- 6	-4.1	-1100 ⁽²⁾	6	
T _J = 150°C	1.8	4.5	7.1	-7.1	-4.5	-1.8			

5.5. MLX92221LUA-AAA-005

DC Operating Parameters V_{DD} = 3.5V to 24V, T_J = -40°C to 165°C

Test Condition	(Dperating Po B _{OP} (mT)	int		Release Poiı B _{RP} (mT)	nt	TC (ppm/ºC)	I _{OFF} (mA)	Active Pole
	Min	Typ ⁽¹⁾	Max	Min	Typ ⁽¹⁾	Max	Typ ⁽¹⁾	Typ ⁽¹⁾	
T _J = -40°C	0.5	2	3.2	-3.2	-2	-0.5			
T」 = 25°C	0.8	1.8	2.8	-2.8	-1.8	-0.8	0 ⁽²⁾	6	South pole
T」 = 150°C	0.3	1.8	3.3	-3.3	-1.8	-0.3			

5.6. MLX92221LUA-AAA-006

DC Operating Parameters V_{DD} = 3.5V to 9.3V, T_J = -40°C to 165°C

Test Condition	Operating Point B _{OP} (mT)		Release Point B _{RP} (mT)		TC (ppm/°C)	I _{OFF} (mA)	Active Pole		
	Min	Typ ⁽¹⁾	Max	Min	Typ ⁽¹⁾	Max	Тур ⁽¹⁾	Typ ⁽¹⁾	
T _J = -40°C	-0.5	1.25	2	-2	-1.25	0.5			
T」 = 25°C	0	0.8	1.6	-1.6	-0.8	0	0 ⁽²⁾	6	South pole
T _J = 150°C	-0.5	1.25	2	-2	-1.25	0.5			

5.7. MLX92221LUA-AAA-007

DC Operating Parameters V_{DD} = 3.5V to 24V, T_J = -40°C to 165°C

Test Condition	Operating Point B _{OP} (mT)		Release Point B _{RP} (mT)		TC (ppm/°C)	I _{ОFF} (mA)	Active Pole		
	Min	Typ ⁽¹⁾	Max	Min	Typ ⁽¹⁾	Max	Тур ⁽¹⁾	Тур ⁽¹⁾	
T _J = -40°C	7.4	11.8	16.3	-7.4	-11.8	-16.3			
T」 = 25°C	7.4	11.8	16.3	-7.4	-11.8	-16.3	0 ⁽²⁾	6	South pole
T _J = 150°C	7.4	11.8	16.3	-7.4	-11.8	-16.3			

1 Typical values are defined at $T_{\text{A}}\text{=+}25^{\circ}\text{C}$ and $V_{\text{DD}}\text{=}12\text{V}$

2 Temperature coefficient is calculated using the following formula:

$$\frac{(B_{OPT2} - B_{RPT2}) - (B_{OPT1} - B_{RPT1})}{(B_{OP25^{\circ}C} - B_{RP25^{\circ}C}) \times (T_2 - T_1)} * 10^6, ppm/^{\circ} C; T_1 = 25^{\circ} C; T_2 = 150^{\circ} C$$

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S N V

South active pole



South active pole

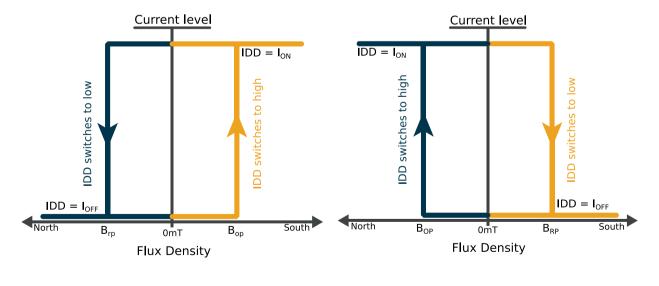
North active pole



North active pole

6. Magnetic Behavior

Note: Latch sensors are inherently Direct South or Direct North Pole Active only.



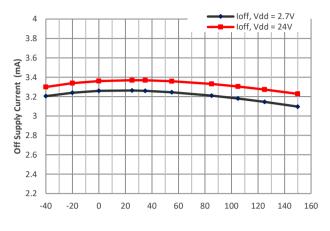


North Active Pole

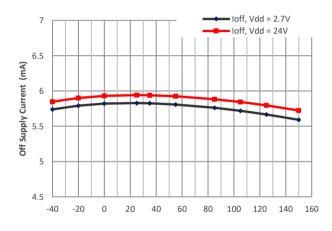


7. Performance Graphs

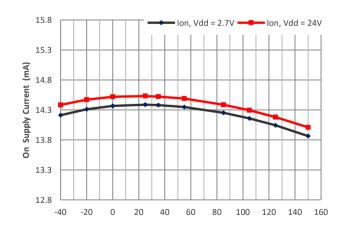
7.1. IOFFLow VS. TJ



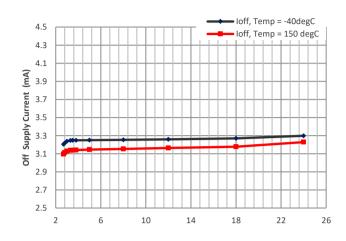




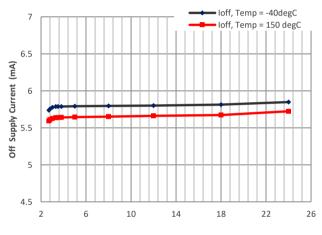




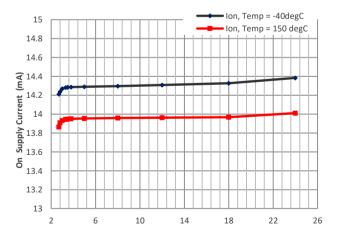
7.4. IOFFLOW VS. VDD





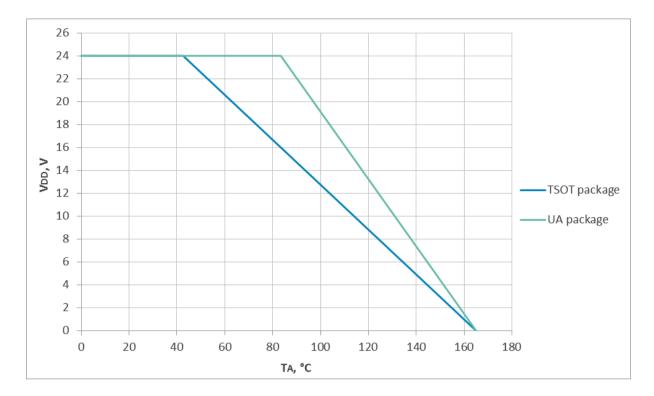




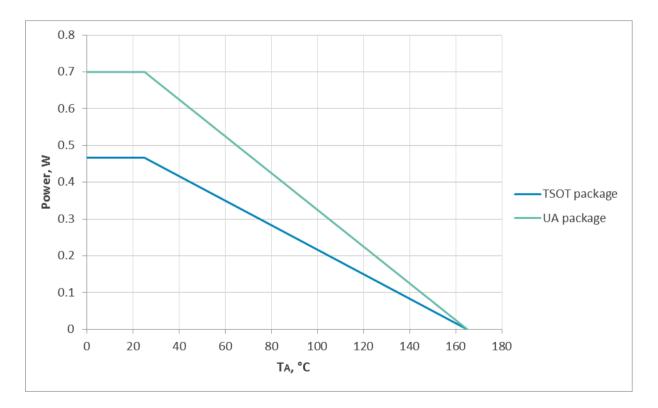




7.7. V_{DD} de-rating



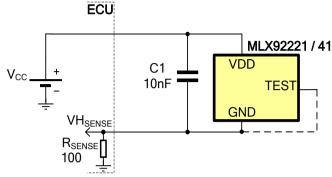
7.8. Power de-rating



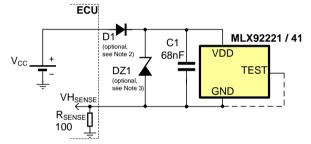


8. Application Information

8.1. Typical Automotive Application Circuit



8.2. Automotive and Harsh, N Environments Application Circuit



Notes:

1. For proper operation, a 10nF to 100nF bypass capacitor should be placed as close as possible to the V_{DD} and ground pin.

2. The device could tolerate negative voltage down to -24V, so if negative transients over supply line V_{PEAK}< -29V are expected, usage of the diode D1 is recommended. Otherwise only R_{SENSE} is sufficient.

When selecting the resistor R_{SENSE} , three points are important:

- the resistor has to limit IDD/IDDREV to 50mA maximum

- the resistor has to withstand the power dissipated in both over voltage conditions $(V_{\text{RSENSE}}^2/R_{\text{SENSE}})$

- the resulting device supply voltage V_{DD} has to be higher than V_{DD} min $(V_{\text{DD}}=V_{\text{CC}}-R_{\text{SENSE}},I_{\text{DD}})$

3. The device could tolerate positive supply voltage up to +27V (until the maximum power dissipation is not exceeded), so if positive transients over supply line with V_{PEAK} 32V are expected, usage a zener diode DZ1 is recommended. The R_{SENSE} -DZ1 network should be sized to limit the voltage over the device below the maximum allowed.

Noisy 8.3. Strobing V_{DD} application (used for

1. For proper operation, a 10nF bypass should be placed as close

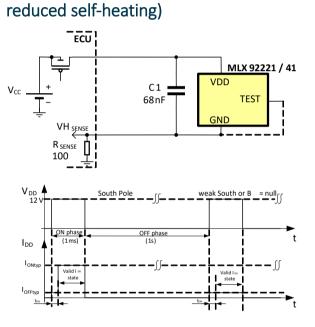
as possible to the V_{DD} and ground.

Recommended.

GND.

For complete emissions protection a C1 = 68nF is

2. The test pin is to be left open or connected to



Notes:

1. Given strobe timing is exemplary only.

2. For proper operation, a 10nF to 100nF bypass capacitor should be placed as close as possible to the V_{DD} and ground pin.



9. Standard information regarding the manufacturability of Melexis products

Our products are classified and qualified regarding soldering technology, solderability and moisture sensitivity level according to following test methods:

Reflow Soldering SMD's (Surface Mount Devices)

- IPC/JEDEC J-STD-020 Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices (classification reflow profiles according to table 5-2)
- EIA/JEDEC JESD22-A113 Preconditioning of Nonhermetic Surface Mount Devices Prior to Reliability Testing (reflow profiles according to table 2)

Wave Soldering SMD's (Surface Mount Devices) and THD's (Through Hole Devices)

- EN60749-20 Resistance of plastic- encapsulated SMD's to combined effect of moisture and soldering heat
- EIA/JEDEC JESD22-B106 and EN60749-15 Resistance to soldering temperature for through-hole mounted devices

Iron Soldering THD's (Through Hole Devices)

• EN60749-15 Resistance to soldering temperature for through-hole mounted devices

Solderability SMD's (Surface Mount Devices) and THD's (Through Hole Devices)

• EIA/JEDEC JESD22-B102 and EN60749-21 Solderability

For all soldering technologies deviating from above mentioned standard conditions (regarding peak temperature, temperature gradient, temperature profile etc) additional classification and qualification tests have to be agreed upon with Melexis.

The application of Wave Soldering for SMD's is allowed only after consulting Melexis regarding assurance of adhesive strength between device and board. <u>http://www.melexis.com/Assets/Soldering-Application-Note-and-Recommendations-5446.aspx</u>

Melexis is contributing to global environmental conservation by promoting **lead free** solutions. For more information on qualifications of **RoHS** compliant products (RoHS = European directive on the Restriction Of the use of certain Hazardous Substances) please visit the quality page on our website: <u>http://www.melexis.com/quality.aspx</u>

10. ESD Precautions

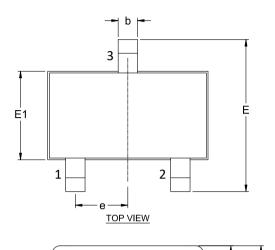
Electronic semiconductor products are sensitive to Electro Static Discharge (ESD). Always observe Electro Static Discharge control procedures whenever handling semiconductor products.

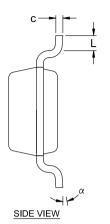


11. Package Information

11.1. TSOT-3L (SE Package)

11.1.1. TSOT-3L – Package dimensions





S≻∑BOL	MINIMUM	MAXIMUM
Α		1.00
A1	0.025	0.10
A2	0.85	0.90
D	2.80	3.00
E	2.60	3.00
E1	1.50	1.70
L	0.30	0.50
b	0.30	0.45
С	0.10	0.20
е	0.95	BSC
e1	1.90	BSC
α	0°	8°



1. ALL DIMENSIONS IN MILLIMETERS (mm) UNLESS OTHERWISE STATED.

2. DIMENSION D DOES NOT INCLUDE MOLD FLASH OR PROTRUSIONS OF MAX 0.15 mm PER SIDE.

A2

A1

3. DIMENSION E DOES NOT INCLUDE MOLD FLASH OR PROTRUSIONS OF MAX 0.25 mm PER SIDE.

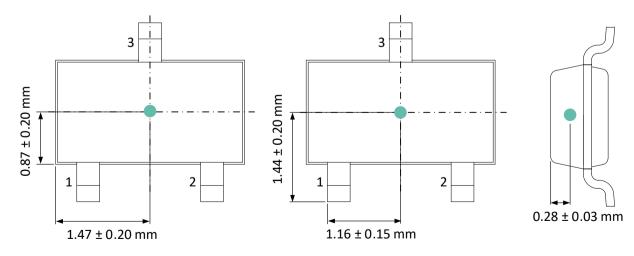
4. DIMENSION & DOES NOT INCLUDE DAMBAR PROTRUSION OF MAX 0.07 mm.

5. DIMENSION L IS THE LENGTH OF THE TERMINAL FOR SOLDERING TO A SUBTRATE.

6. FORMED LEAD SHALL BE PLANAR WITH RESPECT TO ONE ANOTHER WITH 0.076 mm SEATING PLANE.

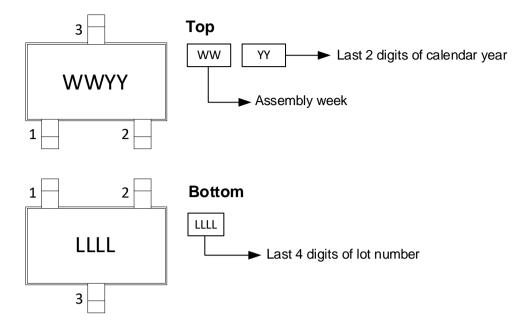
11.1.2. TSOT-3L – Sensitive spot

— e1— — D — <u>SIDE VIEW</u>





11.1.3. TSOT-3L – Package marking / Pin definition

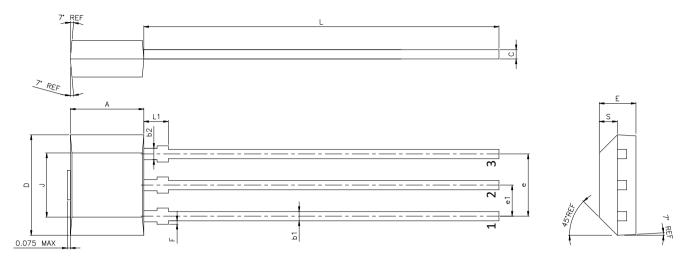


Pin #	Name	Туре	Function
1	VDD	Supply	Supply Voltage pin
2	TEST	I/O	For Melexis use only
3	GND	Ground	Ground pin



11.2. TO92-3L (UA Package)

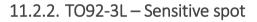
11.2.1. TO92-3L – Package dimensions

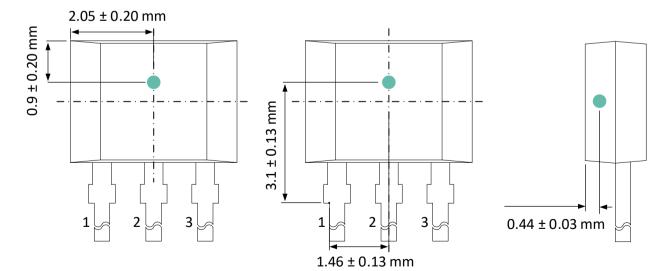


SY⊉BOL	MINIMUM	MAXIMUM
Α	2.90	3.10
D	4.00	4.20
E	1.40	1.60
F	0.00	0.15
J	2.51	2.72
L	14.00	15.00
L1	0.90	1.10
S	0.63	0.84
b1	0.35	0.44
b2	0.43	0.52
С	0.35	0.44
е	2.51	2.57
e1	1.24	1.30

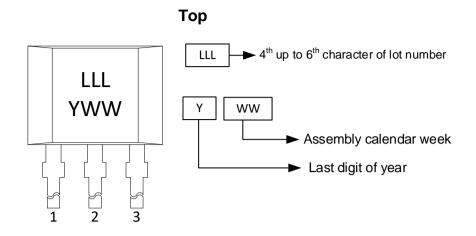
NOTES :

- 1. DIMENSIONS IN MILLIMETERS (mm) UNLESS NOTED OTHERWISE.
- 2. PACKAGE DIMENSIONS DO NOT INCLUDE MOLD FLASHES AND PROTRUSIONS.
- 3. DIMENSION A AND D DO NOT INCLUDE MOLD GATE AND SIDE FLASH (PROTRUSION) of MAXIMUM 0.127 mm PER SIDE.
- 4. THE LEADS MAY BE SLIGHTLY DEFORMED DURING TRANSPORTATION IF PACKED IN BULK (BAG), AFFECTING e1 DIMENSION. IT IS RECOMMENDED TO ORDER RADIAL TAPE (REEL OR AMMOPACK) IF SUCH DEFORMATION IS CRITICAL FOR THE LEAD FORMING PROCESS, EVEN IF MANUAL LOADING INTO THE TOOL IS FORESEEN.





11.2.3. TO92-3L – Package marking / Pin definition



Pin #	Name	Туре	Function
1	VDD	Supply	Supply Voltage pin
2	GND	Ground	Ground pin
3	TEST	I/O	For Melexis use only







12. Contact

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For additional information, please contact our Direct Sales team and get help for your specific needs:

Europe, Africa	Telephone: +32 13 67 04 95		
	Email : sales_europe@melexis.com		
Americas	Telephone: +1 603 223 2362		
	Email : sales_usa@melexis.com		
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